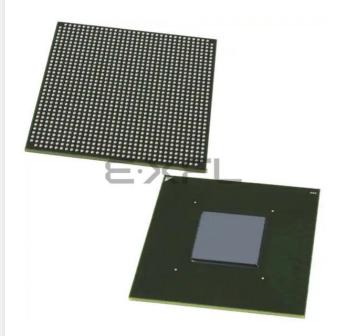
Intel - 5AGXFB7H4F35I5 Datasheet





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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	23780
Number of Logic Elements/Cells	504000
Total RAM Bits	27695104
Number of I/O	544
Number of Gates	-
Voltage - Supply	1.07V ~ 1.13V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	1152-BBGA, FCBGA Exposed Pad
Supplier Device Package	1152-FBGA (35x35)
Purchase URL	https://www.e-xfl.com/product-detail/intel/5agxfb7h4f35i5

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

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1-5

Symbol	Description	Condition	Minimum ⁽¹⁾	Typical	Maximum ⁽¹⁾	Unit
V	Core veltage power supply	-C4, -I5, -C5, -C6	1.07	1.1	1.13	V
V _{CC}	Core voltage power supply	-I3	1.12	1.15	1.18	V
V	Periphery circuitry, PCIe hard IP block,	-C4, -I5, -C5, -C6	1.07	1.1	1.13	V
V _{CCP}	and transceiver PCS power supply	-I3	1.12	1.15	1.18	V
		3.3 V	3.135	3.3	3.465	V
V	Configuration pins power supply	3.0 V	2.85	3.0	3.15	V
V _{CCPGM}		2.5 V	2.375	2.5	2.625	V
		1.8 V	1.71	1.8	1.89	V
V _{CC_AUX}	Auxiliary supply	—	2.375	2.5	2.625	V
V _{CCBAT} ⁽²⁾	Battery back-up power supply	_	1.2	_	3.0	V
	(For design security volatile key register)					
		3.3 V	3.135	3.3	3.465	V
V _{CCPD} ⁽³⁾	I/O pre-driver power supply	3.0 V	2.85	3.0	3.15	V
		2.5 V	2.375	2.5	2.625	V

⁽¹⁾ The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

(2) If you do not use the design security feature in Arria V devices, connect V_{CCBAT} to a 1.5-V, 2.5-V, or 3.0-V power supply. Arria V power-on reset (POR) circuitry monitors V_{CCBAT}. Arria V devices do not exit POR if V_{CCBAT} is not powered up.



⁽³⁾ V_{CCPD} must be 2.5 V when V_{CCIO} is 2.5, 1.8, 1.5, 1.35, 1.25, or 1.2 V. V_{CCPD} must be 3.0 V when V_{CCIO} is 3.0 V. V_{CCPD} must be 3.3 V when V_{CCIO} is 3.3 V.

• Transceiver Specifications for Arria V GT and ST Devices on page 1-29 Provides the specifications for transmitter, receiver, and reference clock I/O pin.

Switching Characteristics

This section provides performance characteristics of Arria V core and periphery blocks.

Transceiver Performance Specifications

Transceiver Specifications for Arria V GX and SX Devices

Table 1-20: Reference Clock Specifications for Arria V GX and SX Devices

Symbol/Description	Condition	Transceiver Speed Grade 4			Transc	- Unit		
Symbol/Description	Condition	Min	Тур	Max	Min	Тур	Max	Onic
Supported I/O standards	1.2 V PCM	L, 1.4 V PCN	IL,1.5 V PCML	, 2.5 V PCMI	L, Differentia	l LVPECL ⁽²³⁾ ,	HCSL, and	LVDS
Input frequency from REFCLK input pins	_	27		710	27		710	MHz
Rise time	Measure at $\pm 60 \text{ mV of}$ differential signal ⁽²⁴⁾			400			400	ps
Fall time	Measure at $\pm 60 \text{ mV}$ of differential signal ⁽²⁴⁾	_		400			400	ps
Duty cycle		45	—	55	45	_	55	%
Peak-to-peak differential input voltage	_	200	_	300 ⁽²⁵⁾ / 2000	200		300 ⁽²⁵⁾ / 2000	mV



⁽²³⁾ Differential LVPECL signal levels must comply to the minimum and maximum peak-to-peak differential input voltage specified in this table.

REFCLK performance requires to meet transmitter REFCLK phase noise specification. (24)

⁽²⁵⁾ The maximum peak-to peak differential input voltage of 300 mV is allowed for DC coupled link.

Symbol	V _{OD} Setting ⁽⁵⁸⁾	V _{OD} Value (mV)	V _{OD} Setting ⁽⁵⁸⁾	V _{OD} Value (mV)
	25	500	53	1060
	26	520	54	1080
	27	540	55	1100
	28	560	56	1120
	29	580	57	1140
	30	600	58	1160
	31	620	59	1180
	32	640	60	1200
	33	660		

Transmitter Pre-Emphasis Levels

The following table lists the simulation data on the transmitter pre-emphasis levels in dB for the first post tap under the following conditions:

- Low-frequency data pattern—five 1s and five 0s
- Data rate—2.5 Gbps

The levels listed are a representation of possible pre-emphasis levels under the specified conditions only and the pre-emphasis levels may change with data pattern and data rate.

Arria V devices only support 1st post tap pre-emphasis with the following conditions:

- The 1st post tap pre-emphasis settings must satisfy $|B| + |C| \le 60$ where $|B| = V_{OD}$ setting with termination value, $R_{TERM} = 100 \Omega$ and |C| = 1st post tap pre-emphasis setting.
- |B| |C| > 5 for data rates < 5 Gbps and |B| |C| > 8.25 for data rates > 5 Gbps.
- $(V_{MAX}/V_{MIN} 1)\% < 600\%$, where $V_{MAX} = |B| + |C|$ and $V_{MIN} = |B| |C|$.

Exception for PCIe Gen2 design: V_{OD} setting = 43 and pre-emphasis setting = 19 are allowed for PCIe Gen2 design with transmit de-emphasis – 6dB setting (pipe_txdeemp = 1'b0) using Altera PCIe Hard IP and PIPE IP cores.



⁽⁵⁸⁾ Convert these values to their binary equivalent form if you are using the dynamic reconfiguration mode for PMA analog controls.

High-Speed I/O Specifications

Table 1-40: High-Speed I/O Specifications for Arria V Devices

When J = 3 to 10, use the serializer/deserializer (SERDES) block. When J = 1 or 2, bypass the SERDES block.

For LVDS applications, you must use the PLLs in integer PLL mode.

The Arria V devices support the following output standards using true LVDS output buffer types on all I/O banks.

- True RSDS output standard with data rates of up to 360 Mbps
- True mini-LVDS output standard with data rates of up to 400 Mbps

Symbol		–I3, –C4		–I5, –C5		-C6			Unit			
		Condition	Min	Тур	Max	Min	Тур	Мах	Min	Тур	Max	Onic
f _{HSCLK_in} (inp Differential I/	out clock frequency) True /O Standards	Clock boost factor W = 1 to $40^{(72)}$	5	_	800	5	_	750	5	_	625	MHz
f _{HSCLK_in} (inp Single-Ended	out clock frequency) I I/O Standards ⁽⁷³⁾	Clock boost factor W = 1 to $40^{(72)}$	5	_	625	5	_	625	5		500	MHz
f _{HSCLK_in} (input clock frequency) Single-Ended I/O Standards ⁽⁷⁴⁾		Clock boost factor W = 1 to $40^{(72)}$	5	_	420	5	_	420	5	_	420	MHz
f _{HSCLK_OUT} (output clock frequency)		5	_	625(75)	5	_	625(75)	5	_	500 ⁽⁷⁵⁾	MHz
Transmitter	True Differential I/O Standards - f _{HSDR} (data rate)	SERDES factor J =3 to $10^{(76)}$	(77)		1250	(77)		1250	(77)		1050	Mbps

⁽⁷³⁾ This applies to DPA and soft-CDR modes only.





⁽⁷²⁾ Clock boost factor (W) is the ratio between the input data rate and the input clock rate.

⁽⁷⁴⁾ This applies to non-DPA mode only.

⁽⁷⁵⁾ This is achieved by using the LVDS clock network.

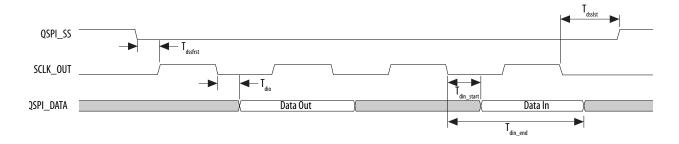
 $^{^{(76)}}$ The F_{max} specification is based on the fast clock used for serial data. The interface F_{max} is also dependent on the parallel clock domain which is design dependent and requires timing analysis.

⁽⁷⁷⁾ The minimum specification depends on the clock source (for example, the PLL and clock pin) and the clock routing resource (global, regional, or local) that you use. The I/O differential buffer and input register do not have a minimum toggle rate.

Symbol	Description	Min	Тур	Max	Unit
T _{din_end}	Input data valid end	$(2 + R_{delay}) \times T_{qspi_clk} - 1.21^{(85)}$		_	ns

Figure 1-8: Quad SPI Flash Timing Diagram

This timing diagram illustrates clock polarity mode 0 and clock phase mode 0.



Related Information

Quad SPI Flash Controller Chapter, Arria V Hard Processor System Technical Reference Manual

Provides more information about Rdelay.

SPI Timing Characteristics

Table 1-52: SPI Master Timing Requirements for Arria V Devices

The setup and hold times can be used for Texas Instruments SSP mode and National Semiconductor Microwire mode.

Symbol	Description	Min	Max	Unit
T _{clk}	CLK clock period	16.67	_	ns
T _{su}	SPI Master-in slave-out (MISO) setup time	8.35 (86)	_	ns

 $^{^{(85)}}$ R_{delay} is set by programming the register <code>qspiregs.rddatacap</code>. For the SoC EDS software version 13.1 and later, Altera provides automatic Quad SPI calibration in the preloader. For more information about R_{delay}, refer to the Quad SPI Flash Controller chapter in the Arria V Hard Processor System Technical Reference Manual.



1-62 SPI Timing Characteristics

Symbol	Description	Min	Мах	Unit
T _h	SPI MISO hold time	1	_	ns
T _{dutycycle}	SPI_CLK duty cycle	45	55	%
T _{dssfrst}	Output delay SPI_SS valid before first clock edge	8		ns
T _{dsslst}	Output delay SPI_SS valid after last clock edge	8		ns
T _{dio}	Master-out slave-in (MOSI) output delay	-1	1	ns

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⁽⁸⁶⁾ This value is based on rx_sample_dly = 1 and spi_m_clk = 120 MHz. spi_m_clk is the internal clock that is used by SPI Master to derive it's SCLK_OUT. These timings are based on rx_sample_dly of 1. This delay can be adjusted as needed to accommodate slower response times from the slave. Note that a delay of 0 is not allowed. The setup time can be used as a reference starting point. It is very crucial to do a calibration to get the correct rx_sample_dly value because each SPI slave device may have different output delay and each application board may have different path delay. For more information about rx_sample_delay, refer to the SPI Controller chapter in the Hard Processor System Technical Reference Manual.

After the Boot ROM code exits and control is passed to the preloader, software can adjust the value of drvsel and smplsel via the system manager. drvsel can be set from 1 to 7 and smplsel can be set from 0 to 7. While the preloader is executing, the values for SDMMC_CLK and SDMMC_CLK_OUT increase to a maximum of 200 MHz and 50 MHz respectively.

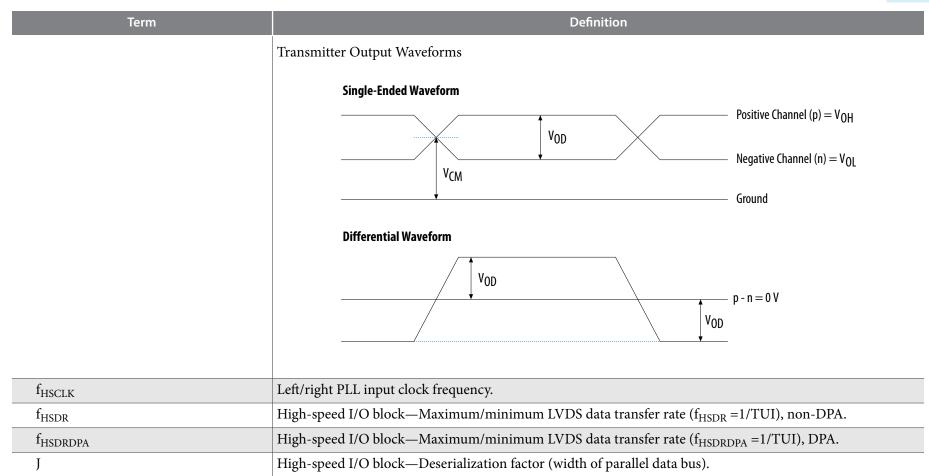
The SD/MMC interface calibration support will be available in a future release of the preloader through the SoC EDS software update.

Symbol	Description	Min	Мах	Unit
	SDMMC_CLK clock period (Identification mode)	20	_	ns
T _{sdmmc_clk} (internal reference clock)	SDMMC_CLK clock period (Default speed mode)	5	_	ns
	SDMMC_CLK clock period (High speed mode)	5	_	ns
	SDMMC_CLK_OUT clock period (Identification mode)	2500	_	ns
T _{sdmmc_clk_out} (interface output clock)	SDMMC_CLK_OUT clock period (Default speed mode)	40	_	ns
	SDMMC_CLK_OUT clock period (High speed mode)	20	_	ns
T _{dutycycle}	SDMMC_CLK_OUT duty cycle	45	55	%
T _d	SDMMC_CMD/SDMMC_D output delay	$\frac{(T_{sdmmc_clk} \times drvsel)/2}{-1.23}$	$\begin{array}{c} (\mathrm{T}_{sdmmc_clk} \times \texttt{drvsel})/2 \\ + 1.69^{\ (87)} \end{array}$	ns
T _{su}	Input setup time	$1.05 - (T_{sdmmc_clk} \times smplsel)/2^{(88)}$		ns
T _h	Input hold time	$\frac{(T_{sdmmc_clk} \times \texttt{smplsel})}{2^{(88)}}$	—	ns

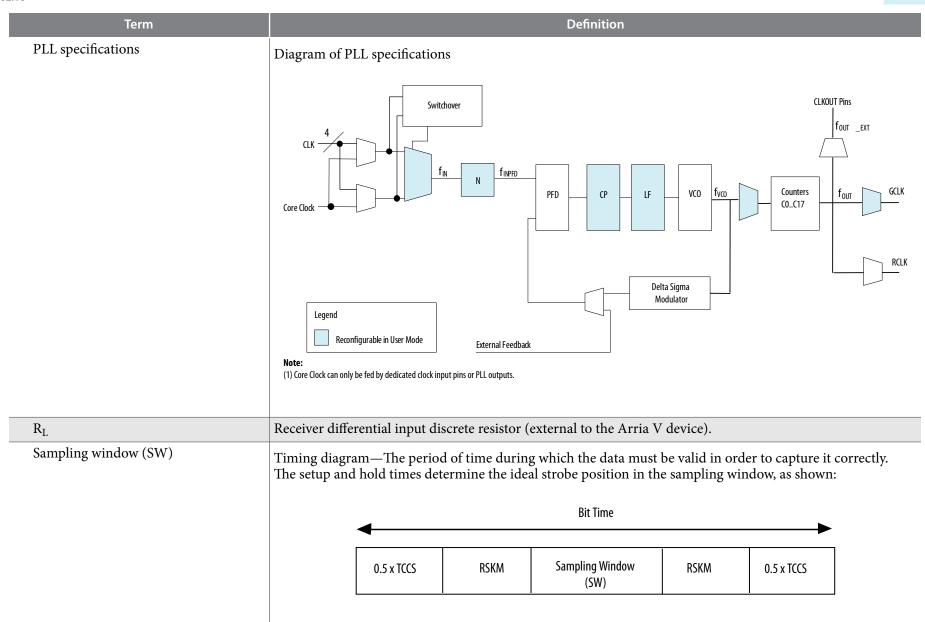


⁽⁸⁷⁾ drvsel is the drive clock phase shift select value.

⁽⁸⁸⁾ smplsel is the sample clock phase shift select value.







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2-2 Absolute Maximum Ratings

Lower number refers to faster speed grade.

L = Low power devices.

Transceiver Speed Grade	Core Speed Grade						
	C3	C4	I3L	14			
2	Yes	_	Yes	-			
3		Yes		Yes			

Absolute Maximum Ratings

Absolute maximum ratings define the maximum operating conditions for Arria V GZ devices. The values are based on experiments conducted with the devices and theoretical modeling of breakdown and damage mechanisms. The functional operation of the device is not implied for these conditions.

Caution: Conditions other than those listed in the following table may cause permanent damage to the device. Additionally, device operation at the absolute maximum ratings for extended periods of time may have adverse effects on the device.

Table 2-2: Absolute Maximum Ratings for Arria V GZ Devices

Symbol	Description	Minimum	Maximum	Unit
V _{CC}	Power supply for core voltage and periphery circuitry	-0.5	1.35	V
V _{CCPT}	Power supply for programmable power technology	-0.5	1.8	V
V _{CCPGM}	Power supply for configuration pins	-0.5	3.9	V
V _{CC_AUX}	Auxiliary supply for the programmable power technology	-0.5	3.4	V
V _{CCBAT}	Battery back-up power supply for design security volatile key register	-0.5	3.9	V
V _{CCPD}	I/O pre-driver power supply	-0.5	3.9	V
V _{CCIO}	I/O power supply	-0.5	3.9	V
V _{CCD_FPLL}	PLL digital power supply	-0.5	1.8	V
V _{CCA_FPLL}	PLL analog power supply	-0.5	3.4	V



Symbol	Description	Minimum	Maximum	Unit
VI	DC input voltage	-0.5	3.8	V
T _J	Operating junction temperature	-55	125	°C
T _{STG}	Storage temperature (No bias)	-65	150	°C
I _{OUT}	DC output current per pin	-25	40	mA

Table 2-3: Transceiver Power Supply Absolute Conditions for Arria V GZ Devices

Symbol	Description	Minimum	Maximum	Unit
V _{CCA_GXBL}	Transceiver channel PLL power supply (left side)	-0.5	3.75	V
V _{CCA_GXBR}	Transceiver channel PLL power supply (right side)	-0.5	3.75	V
V _{CCHIP_L}	Transceiver hard IP power supply (left side)	-0.5	1.35	V
V _{CCHSSI_L}	Transceiver PCS power supply (left side)	-0.5	1.35	V
V _{CCHSSI_R}	Transceiver PCS power supply (right side)	-0.5	1.35	V
V _{CCR_GXBL}	Receiver analog power supply (left side)	-0.5	1.35	V
V _{CCR_GXBR}	Receiver analog power supply (right side)	-0.5	1.35	V
V _{CCT_GXBL}	Transmitter analog power supply (left side)	-0.5	1.35	V
V _{CCT_GXBR}	Transmitter analog power supply (right side)	-0.5	1.35	V
V _{CCH_GXBL}	Transmitter output buffer power supply (left side)	-0.5	1.8	V
V _{CCH_GXBR}	Transmitter output buffer power supply (right side)	-0.5	1.8	V

Maximum Allowed Overshoot and Undershoot Voltage

During transitions, input signals may overshoot to the voltage shown in the following table. They may also undershoot to -2.0 V for input currents less than 100 mA and periods shorter than 20 ns.



Symbol	Description	Condition	Minimum ⁽¹¹⁴⁾	Typical	Maximum ⁽¹¹⁴⁾	Unit
V _{CCPT}	Power supply for programmable power technology	_	1.45	1.50	1.55	V
V _{CC_AUX}	Auxiliary supply for the programmable power technology	_	2.375	2.5	2.625	V
V _{CCPD} ⁽¹¹⁶	I/O pre-driver (3.0 V) power supply		2.85	3.0	3.15	V
)	I/O pre-driver (2.5 V) power supply		2.375	2.5	2.625	V
	I/O buffers (3.0 V) power supply	_	2.85	3.0	3.15	V
	I/O buffers (2.5 V) power supply		2.375	2.5	2.625	V
	I/O buffers (1.8 V) power supply		1.71	1.8	1.89	V
V _{CCIO}	I/O buffers (1.5 V) power supply	_	1.425	1.5	1.575	V
	I/O buffers (1.35 V) power supply	_	1.283	1.35	1.45	V
	I/O buffers (1.25 V) power supply	_	1.19	1.25	1.31	V
	I/O buffers (1.2 V) power supply	_	1.14	1.2	1.26	V
	Configuration pins (3.0 V) power supply	_	2.85	3.0	3.15	V
V _{CCPGM}	Configuration pins (2.5 V) power supply	_	2.375	2.5	2.625	V
	Configuration pins (1.8 V) power supply	_	1.71	1.8	1.89	V
V _{CCA} _	PLL analog voltage regulator power supply	_	2.375	2.5	2.625	V
V _{CCD} FPLL	PLL digital voltage regulator power supply	_	1.45	1.5	1.55	V
V _{CCBAT} (117	Battery back-up power supply (For design security volatile key register)	_	1.2	—	3.0	V

⁽¹¹⁴⁾ The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements.
Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.



⁽¹¹⁶⁾ V_{CCPD} must be 2.5 V when V_{CCIO} is 2.5, 1.8, 1.5, 1.35, 1.25 or 1.2 V. V_{CCPD} must be 3.0 V when V_{CCIO} is 3.0 V.

⁽¹¹⁷⁾ If you do not use the design security feature in Arria V GZ devices, connect V_{CCBAT} to a 1.2- to 3.0-V power supply. Arria V GZ power-on-reset (POR) circuitry monitors V_{CCBAT}. Arria V GZ devices do not exit POR if V_{CCBAT} is not powered up.

Symbol	Description	Minimum ⁽¹¹⁸⁾	Typical	Maximum ⁽¹¹⁸⁾	Unit	
		0.82	0.85	0.88		
V _{CCR_GXBL} ⁽¹²¹⁾	Receiver analog power supply (left side)	0.97	1.0	1.03	V	
		1.03	1.05	1.07		
		0.82	0.85	0.88		
V _{CCR_GXBR} ⁽¹²¹⁾	Receiver analog power supply (right side)	0.97	1.0	1.03	V	
		1.03	1.05	1.07		
	Transmitter analog power supply (left side)	0.82	0.85	0.88	V	
V _{CCT_GXBL} ⁽¹²¹⁾		0.97	1.0	1.03		
		1.03	1.05	1.07		
	Transmitter analog power supply (right side)	0.82	0.85	0.88		
V _{CCT_GXBR} ⁽¹²¹⁾		0.97	1.0	1.03	V	
		1.03	1.05	1.07		
V _{CCH_GXBL}	Transmitter output buffer power supply (left side)	1.425	1.5	1.575	V	
V _{CCH_GXBR}	Transmitter output buffer power supply (right side)	1.425	1.5	1.575	V	



⁽¹¹⁸⁾ This value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

⁽¹²¹⁾ This supply must be connected to 1.0 V if the transceiver is configured at a data rate > 6.5 Gbps, and to 1.05 V if configured at a data rate > 10.3 Gbps when DFE is used. For data rate up to 6.5 Gbps, you can connect this supply to 0.85 V.

I/O Standard	V _{CCIO} (V) ⁽¹²⁸⁾		V _{ID} (mV) ⁽¹²⁹⁾		V _{ICM(DC)} (V)		V _{OD} (V) ⁽¹³⁰⁾		0)	V _{OCM} (V) ⁽¹³⁰⁾					
	Min	Тур	Max	Min	Condition	Max	Min	Condition	Max	Min	Тур	Max	Min	Тур	Max
RSDS (HIO) (133)	2.375	2.5	2.625	100	V _{CM} = 1.25 V		0.3		1.4	0.1	0.2	0.6	0.5	1.2	1.4
Mini- LVDS (HIO) (134)	2.375	2.5	2.625	200	_	600	0.4	_	1.325	0.25		0.6	1	1.2	1.4
LVPECL	_		_	300			0.6	D _{MAX} ≤ 700 Mbps	1.8	_				_	_
(135), (136)			_	300			1	D _{MAX} > 700 Mbps	1.6	_	_			_	_

Related Information

Glossary on page 2-73



⁽¹²⁸⁾ Differential inputs are powered by VCCPD which requires 2.5 V.

⁽¹²⁹⁾ The minimum VID value is applicable over the entire common mode range, VCM.

RL range: $90 \le RL \le 110 \Omega$. (130)

⁽¹³³⁾ For optimized RSDS receiver performance, the receiver voltage input range must be between 0.25 V to 1.45 V.

⁽¹³⁴⁾ For optimized Mini-LVDS receiver performance, the receiver voltage input range must be between 0.3 V to 1.425 V.

⁽¹³⁵⁾ LVPECL is only supported on dedicated clock input pins.

⁽¹³⁶⁾ For optimized LVPECL receiver performance, the receiver voltage input range must be between 0.85 V to 1.75 V for data rate above 700 Mbps and 0.45 V to 1.95 V for data rate below 700 Mbps.

Core Performance Specifications

Clock Tree Specifications

Table 2-33: Clock Tree Performance for Arria V GZ Devices

Symbol	Perfor	Unit	
Synbol	C3, I3L	C4, I4	Onit
Global and Regional Clock	650	580	MHz
Periphery Clock	500	500	MHz

PLL Specifications

Table 2-34: PLL Specifications for Arria V GZ Devices

Symbol	Parameter	Min	Тур	Max	Unit
f _{IN} ⁽¹⁶⁷⁾	Input clock frequency (C3, I3L speed grade)	5	_	800	MHz
IIN	Input clock frequency (C4, I4 speed grade)	5	_	650	MHz
f _{INPFD}	Input frequency to the PFD	5		325	MHz
f _{FINPFD}	Fractional Input clock frequency to the PFD	50	_	160	MHz
f _{VCO} ⁽¹⁶⁸⁾	PLL VCO operating range (C3, I3L speed grade)	600		1600	MHz
IVCO	PLL VCO operating range (C4, I4 speed grade)	600	_	1300	MHz
t _{EINDUTY}	Input clock or external feedback clock input duty cycle	40		60	%

⁽¹⁶⁷⁾ This specification is limited in the Quartus II software by the I/O maximum frequency. The maximum I/O frequency is different for each I/O standard.

⁽¹⁶⁸⁾ The VCO frequency reported by the Quartus II software in the **PLL Usage Summary** section of the compilation report takes into consideration the VCO post-scale counter K value. Therefore, if the counter K has a value of 2, the frequency reported can be lower than the f_{VCO} specification.

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Symbol	Parameter	Min	Тур	Мах	Unit
t _{INCCJ} ⁽¹⁷¹⁾ , ⁽¹⁷²⁾	Input clock cycle-to-cycle jitter ($f_{REF} \ge 100 \text{ MHz}$)	—	_	0.15	UI (p-p)
'INCCJ , , , , , ,	Input clock cycle-to-cycle jitter ($f_{REF} < 100 \text{ MHz}$)	-750		+750	ps (p-p)
t _{outpj_dc} ⁽¹⁷³⁾	Period Jitter for dedicated clock output in integer PLL ($f_{OUT} \ge 100 \text{ MHz}$)	_	_	175	ps (p-p)
COUTPJ_DC	Period Jitter for dedicated clock output in integer PLL (f _{OUT} < 100 Mhz)	_		17.5	mUI (p-p)
(173)	Period Jitter for dedicated clock output in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$)	_		$250^{(176)}, \\ 175^{(174)}$	ps (p-p)
t _{FOUTPJ_DC} ⁽¹⁷³⁾	Period Jitter for dedicated clock output in fractional PLL (f _{OUT} < 100 MHz)	_	_	$25^{(176)}$, 17.5 ⁽¹⁷⁴⁾	mUI (p-p)
t	Cycle-to-cycle Jitter for a dedicated clock output in integer PLL ($f_{OUT} \ge 100 \text{ MHz}$)	_	_	175	ps (p-p)
t _{OUTCCJ_DC} ⁽¹⁷³⁾	Cycle-to-cycle Jitter for a dedicated clock output in integer PLL (f _{OUT} < 100 MHz)	_		17.5	mUI (p-p)
(173)	Cycle-to-cycle Jitter for a dedicated clock output in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$)	—		250 ⁽¹⁷⁶⁾ , 175 ⁽¹⁷⁴⁾	ps (p-p)
t _{FOUTCCJ_DC} ⁽¹⁷³⁾	Cycle-to-cycle Jitter for a dedicated clock output in fractional PLL ($f_{OUT} < 100 \text{ MHz}$)			$25^{(176)}$, 17.5 ⁽¹⁷⁴⁾	mUI (p-p)

⁽¹⁷¹⁾ A high input jitter directly affects the PLL output jitter. To have low PLL output clock jitter, you must provide a clean clock source with jitter < 120 ps. ⁽¹⁷²⁾ The f_{REF} is fIN/N specification applies when N = 1.

⁽¹⁷⁴⁾ This specification only covered fractional PLL for low bandwidth. The f_{VCO} for fractional value range 0.20–0.80 must be \geq 1200 MHz.



⁽¹⁷³⁾ Peak-to-peak jitter with a probability level of 10⁻¹² (14 sigma, 99.999999999974404% confidence level). The output jitter specification applies to the intrinsic jitter of the PLL, when an input jitter of 30 ps is applied. The external memory interface clock output jitter specifications use a different measurement method and are available in the "Worst-Case DCD on Arria V GZ I/O Pins" table.

2-50 Soft CDR Mode High-Speed I/O Specifications

Standard	Training Pattern	Number of Data Transitions in One Repetition of the Training Pattern	Number of Repetitions per 256 Data Transitions (201)	Maximum
Parallel Rapid I/O	00001111	2	128	640 data transitions
r araner Rapid 1/0	10010000	4	64	640 data transitions
Miscellanoous	10101010	8	32	640 data transitions
Miscellaneous	01010101	8	32	640 data transitions

Soft CDR Mode High-Speed I/O Specifications

Table 2-44: High-Speed I/O Specifications for Arria V GZ Devices

When J = 3 to 10, use the serializer/deserializer (SERDES) block.

When J = 1 or 2, bypass the SERDES block.

Symbol	Conditions	C3, I3L				Unit		
Symbol		Min	Тур	Мах	Min	Тур	Мах	Unit
Soft-CDR ppm tolerance	—		_	300		—	300	± ppm





⁽²⁰¹⁾ This is the number of repetitions for the stated training pattern to achieve the 256 data transitions.

2-64 FPP Configuration Timing when DCLK to DATA[] > 1

Symbol	Parameter	Minimum	Maximum	Unit
t _{CD2CU}	CONF_DONE high to CLKUSR enabled	$4 \times \text{maximum DCLK}$ period	_	—
t _{CD2UMC}	CONF_DONE high to user mode with CLKUSR option on	t_{CD2CU} + (8576 × CLKUSR period) (215)	_	—

Related Information

- DCLK-to-DATA[] Ratio (r) for FPP Configuration on page 2-57
- Configuration, Design Security, and Remote System Upgrades in Arria V Devices

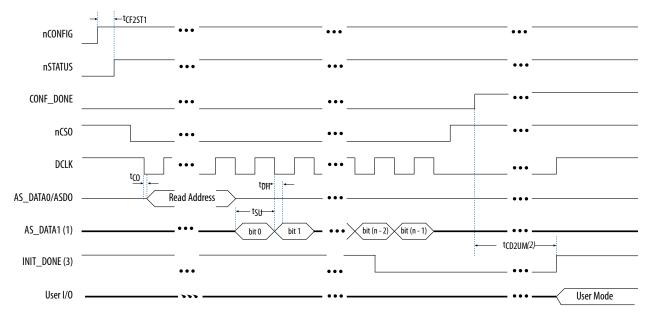




⁽²¹⁵⁾ To enable the CLKUSR pin as the initialization clock source and to obtain the maximum frequency specification on these pins, refer to the "Initialization" section of the *Configuration, Design Security, and Remote System Upgrades in Arria V Devices* chapter.

Active Serial Configuration Timing

Figure 2-9: AS Configuration Timing



Timing waveform for the active serial (AS) x1 mode and AS x4 mode configuration timing.

Notes:

1. If you are using AS ×4 mode, this signal represents the AS_DATA[3..0] and ERCQ sends in 4-bits of data for each DCLKcycle.

2. The initialization clock can be from internal oscillator or CLKUSR pin

3. After the option bit to enable the INIT_DONE pin is configured into the device, the INIT_DONE ges low.

Table 2-58: AS Timing Parameters for AS x1 and AS x4 Configurations in Arria V GZ Devices

The minimum and maximum numbers apply only if you choose the internal oscillator as the clock source for initializing the device.

t_{CF2CD}, t_{CF2ST0}, t_{CFG}, t_{STATUS}, and t_{CF2ST1} timing parameters are identical to the timing parameters for PS mode listed in the "PS Timing Parameters for Arria V GZ Devices" table.



Glossary

Table 2-68: Glossary

